

Nb₃Sn Conductor Technology for the FCC

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Introduction – Nb₃Sn for FCC



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Property	Units	Values
Strand diameter	(mm)	0.5 mm to 1.0 mm
J _c (4.2 K, 16 T)	(A/mm²)	≥ 1500
μ _o M(1 T, 4.2 K)	(mT)	≤ 150
σ(μ _o M)(1 T, 4.2 K)	(%)	≤ 4 .5
D _{eff}	(μ m)	≤ 20
RRR		≥ 150
Unit Length	(km)	≥ 5 km

"Targets for R&D on Nb₃Sn conductor for High Energy Physics", Ballarino and Bottura



	Property	Units	Values
<	Strand diameter	(mm)	0.5 mm to 1.0 mm
	J _c (4.2 K, 16 T)	(A/mm²)	≥ 1500
	μ _o M(1 T, 4.2 K)	(mT)	≤ 150
	σ(μ _o M)(1 T, 4.2 K)	(%)	≤ 4 .5
<	D _{eff}	(μ m)	≤ 20
	RRR		≥ 150
	Unit Length	(km)	≥ 5 km

$D_{eff} \le 20 \mu m$ in 0.5 - 1 mm diameter strands



- Strand diameter the issue is relationship to D_{eff}
 - Single Barrier, "ITER" type strands, D_{eff} ~20-30 μm at 0.82 mm (after HT, due to merging)
 - For distributed barrier strands (RRP[®], PIT, tube)
 D_s is tough challenge with a single restack of appreciable weight (large aspect ratio)

	D _s (stack count) in μm						
wire dia.	169 217 271 331 397 469 547						
1.0 mm	59	52	47	42	39	35	33
0.9 mm	53	47	42	38	35	32	30
0.85 mm	50	44	40	36	33	30	28
0.8 mm	47	42	37	34	31	28	26
0.7 mm	41	36	33	30	27	25	23
0.6 mm	35	31	28	25	23	21	20
0.5 mm	29	26	23	21	19	18	16





$D_{eff} \le 20 \mu m$ in 0.5 - 1 mm diameter strands



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- A "double restack" restacking the restack can access the smaller D_s at the desired wire size range
 - Need subelements tolerant to a high true strain (i.e. ductile)
 - Difficult to maintain high I_c value, as double restack adds copper to the cross section (i.e. dilutes superconductor fraction)



(illustration) 7 stack X 61 stack $D_s \sim 20 \ \mu m @ 0.8 \ mm$



	Property	Units	Values
	Strand diameter	(mm)	0.5 mm to 1.0 mm
\triangleleft	J _c (4.2 K, 16 T)	(A/mm ²)	≥ 1500
	μ _o M(1 T, 4.2 K)	(mT)	≤ 150
	σ(μ _o M)(1 T, 4.2 K)	(%)	≤ 4 .5
	D _{eff}	(μ m)	≤ 20
	RRR		≥ 150
	Unit Length	(km)	≥ 5 km

J_c(4.2 K, 16 T) > 1500 A/mm²



- The most critical parameter need the J_c to get the field
 - present RRP[®] design is close for $D_s > 80 \ \mu m$





- J_c decreases significantly for D_s below ~50 μ m
 - Need better understanding of tin / bronze diffusion and the interaction with Nb-Sn-Cu ternary as $\mathsf{D}_{s}{\downarrow}$
 - Collaborations with Sanabria (FSU), Pong (LBL)



RRP reacted 210°C/48hr + 400°C/48hr, Courtesy of FSU (Peter Lee, Charlie Sanabria)



	Property	Units	Values
	Strand diameter	(mm)	0.5 mm to 1.0 mm
	J _c (4.2 K, 16 T)	(A/mm ²)	≥ 1500
\triangleleft	μ _o M(1 T, 4.2 K)	(mT)	≤ 150
<	σ(μ _o M)(1 T, 4.2 K)	(%)	≤ 4 .5
	D _{eff}	(μ m)	≤ 20
	RRR		≥ 150
	Unit Length	(km)	\geq 5 km

μ_{o} M(1 T, 4.2 K) < 150mT, $\sigma \le 4.5\%$



- D_{eff} on order of 20 μ m is easier in single barrier strands, but layer J_c is the problem
 - Can layer J_c be increased by APC?
 - σ is a challenge driven by J_c spread



μ_{o} M(1 T, 4.2 K) < 150mT, $\sigma \le$ 4.5%



- Distributed barrier RRP[®] 3-4x too high
 - Flux jumps also an issue





μ_o M(1 T, 4.2 K) < 150mT, $\sigma \le 4.5\%$



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• What if D_s is large but D_{eff} is small?



- Depress J_c in low fields higher B_{c2}
- σ more challenging than single barrier J_c spread wider



	Property	Units	Values
	Strand diameter	(mm)	0.5 mm to 1.0 mm
	J _c (4.2 K, 16 T)	(A/mm ²)	≥ 1500
	μ _o M(1 T, 4.2 K)	(mT)	≤ 150
	σ(μ _o M)(1 T, 4.2 K)	(%)	≤ 4 .5
	D _{eff}	(μ m)	≤ 20
<	RRR		≥ 150
	Unit Length	(km)	≥ 5 km





 Improved RRR throughout billet by reducing sources of variation in design and in processing



- High RRR in small D_s distributed barrier strand still a challenge
- 400 +650C/50hr 300 US DOE CDP R&D RRR Barrier thickness studies 200 169 stack, Nb:Sn 3.6:1 +665C/50hr 100 0 20 30 40 50 60 **D**_s(μm)
- Is RRR > 150 in round strand an absolute requirement? What about RRR after cabling? Ever possible to use RRR > 60?



RRR > 150



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Single barrier (ITER style strands) – Ta barriers can remain intact during deformation better than the subelements inside



Extracted strand from CICC, "Challenges and Status of ITER conductor production", Devred et al



	Property	Units	Values
	Strand diameter	(mm)	0.5 mm to 1.0 mm
	J _c (4.2 K, 16 T)	(A/mm ²)	≥ 1500
	μ _o M(1 T, 4.2 K)	(mT)	≤ 15 0
	σ(μ _o M)(1 T, 4.2 K)	(%)	≤ 4 .5
	D _{eff}	(μ m)	≤ 20
	RRR		≥ 15 0
\triangleleft	Unit Length	(km)	≥ 5 km

Minimum Length > 5 km



- Internal tin = (relatively) small billet volume
- Typical piece length depends on wire diameter?
 - 0.5 mm length 4x 1.0 mm length for same weight
- Need to consider total cost of cable (strand vs. cable yield)
 - As billets are relatively small, long lengths = limited yield
- ITER experience: 70 tons of production, averaged ~6km @ 0.82mm
 - However this was a more "simple" strand



Property	Units	Values	RRP [®]	Single bar.
Strand diameter	(mm)	0.5 mm to 1.0 mm	\checkmark	\checkmark
J _c (4.2 K, 16 T)	(A/mm ²)	≥ 1500	close	X
μ _o M(1 T, 4.2 K)	(mT)	≤ 150	Х	close?
σ(μ _o M)(1 T, 4.2 K)	(%)	≤ 4 .5	Х	X
D _{eff}	(μ m)	≤ 20	X	\checkmark
RRR		≥ 150	?	\checkmark
Unit Length	(km)	≥ 5 km	?	?





- FCC Nb₃Sn targets present new challenges
- Progress is being made in understanding how to preserve J_c and RRR as D_s is decreased
- New breakthrough needed: keep high layer J_c of RRP[®], but with the filament spacing and layout of single barrier strand



Visual metaphor for future FCC strand!